

REVISIONS

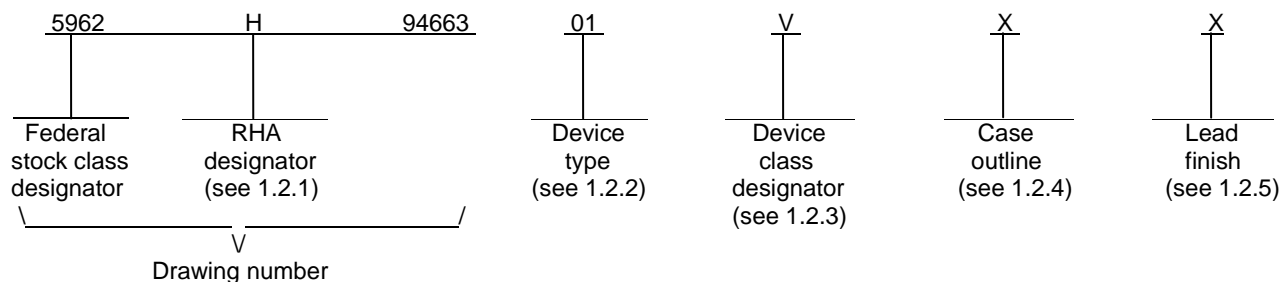
LTR	DESCRIPTION	DATE (YR-MO-DA)	APPROVED
A	Add device types 04, 05, and 06. Modify boilerplate to include rad hard requirements. Editorial changes throughout. – TVN	96-03-13	Monica L. Poelking
B	Add device types 07, 08, and 09. Update boilerplate. Editorial changes throughout. – TVN	98-08-27	Monica L. Poelking
C	In table I, change I_{IN} limits; add footnote to I_{DDQ} ; add t_c in power-up master reset timing section; add footnote to V_{OS} and V_{DIS} . Correct the JTAG timing waveforms. Change footnote 3/ in table III. – TVN	99-04-28	Monica L. Poelking
D	Add device types 10 and 11. Editorial changes throughout. - TVN	00-06-27	Monica L. Poelking
E	Add notes to memory write and memory read waveforms. Editorial changes throughout. – TVN	01-03-13	Thomas M. Hess
F	Correct dimension L for case outline Y in figure 1. Also, correct footnote 1/ for radiation exposure connections in figure 6. – TVN	01-07-27	Thomas M. Hess
G	Specify PDA criteria in table IIA footnotes and in paragraph 4.2.2b. – CFS	03-10-28	Thomas M. Hess
H	Update boilerplate paragraphs to current MIL-PRF-38535 requirements. – CFS	09-03-16	Thomas M. Hess
J	Add detail B for figure 1, case outline Y. - PHN	11-03-22	David J. Corbett
K	Update radiation features in section 1.5 and SEP table IB per GIDEP. Delete class M requirements throughout. - MAA	13-05-20	Thomas M. Hess

REV	K	K	K																														
SHEET	35	36	37																														
REV	K	K	K	K	K	K	K	K	K	K	K	K	K	K	K	K	K	K	K	K	K												
SHEET	15	16	17	18	19	20	21	22	23	24	25	26	27	28	29	30	31	32	33	34													
REV STATUS OF SHEETS				REV			K	K	K	K	K	K	K	K	K	K	K	K	K	K	K												
				SHEET			1	2	3	4	5	6	7	8	9	10	11	12	13	14													
PMIC N/A				PREPARED BY Thomas M. Hess						DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990 http://www.landandmaritime.dla.mil																							
STANDARD MICROCIRCUIT THIS DRAWING IS AVAILABLE FOR USE BY ALL DEPARTMENTS AND AGENCIES OF THE DEPARTMENT OF DEFENSE AMSC N/A				CHECKED BY Thomas M. Hess																													
				APPROVED BY Monica L. Poelking																													
				DRAWING APPROVAL DATE 95-03-31																													
				REVISION LEVEL K						SIZE A	CAGE CODE 67268	5962-94663																					
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1. SCOPE

1.1 Scope. This drawing documents two product assurance class levels consisting of high reliability (device class Q) and space application (device class V). A choice of case outlines and lead finishes are available and are reflected in the Part or Identifying Number (PIN). When available, a choice of Radiation Hardness Assurance (RHA) levels is reflected in the PIN.

1.2 PIN. The PIN is as shown in the following example:



1.2.1 RHA designator. Device classes Q and V RHA marked devices meet the MIL-PRF-38535 specified RHA levels and are marked with the appropriate RHA designator. A dash (-) indicates a non-RHA device.

1.2.2 Device type(s). The device type(s) identify the circuit function as follows:

Device type	Generic number	Circuit function
01	69151-LX15	Serial microcoded multi-mode intelligent terminal with 15-volt transceiver
02	69151-DX	Serial microcoded multi-mode intelligent terminal with 5-volt transceiver
03	69151-LX12	Serial microcoded multi-mode intelligent terminal with 12-volt transceiver
04	69151-LXE15	Enhanced serial microcoded multi-mode intelligent terminal with 15-volt transceiver radiation hardened
05	69151-DXE	Enhanced serial microcoded multi-mode intelligent terminal with 5-volt transceiver radiation hardened
06	69151-LXE12	Enhanced serial microcoded multi-mode intelligent terminal with 12-volt transceiver
07	69151-LXE15	Enhanced serial microcoded multi-mode intelligent terminal with 15-volt transceiver
08	69151-DXE	Enhanced serial microcoded multi-mode intelligent terminal with 5-volt transceiver
09	69151-LXE12	Enhanced serial microcoded multi-mode intelligent terminal with 12-volt transceiver
10	69151-LXE15	Enhanced serial microcoded multi-mode intelligent terminal with 15-volt transceiver radiation hardened
11	69151-DXE	Enhanced serial microcoded multi-mode intelligent terminal with 5-volt transceiver radiation hardened

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1.2.3 Device class designator. The device class designator is a single letter identifying the product assurance level as follows:

Device class

Q or V

Device requirements documentation

Certification and qualification to MIL-PRF-38535

1.2.4 Case outline(s). The case outline(s) are as designated in MIL-STD-1835 and as follows:

<u>Outline letter</u>	<u>Descriptive designator</u>	<u>Terminals</u>	<u>Package style</u>
X	See figure 1	100	Pin grid array <u>1/</u>
Y	See figure 1	100	Leaded chip carrier with nonconductive tier bar

1.2.5 Lead finish. The lead finish is as specified in MIL-PRF-38535 for device classes Q and V.

1.3 Absolute maximum ratings. 2/

Storage temperature range (T_{STG})	-65°C to +150°C
Operating case temperature range (T_C)	-55°C to +125°C
Transceiver supply voltage (V_{EE}):	
Device types 01, 03, 04, 06, 07, 09, 10	-22 V dc
Transceiver supply voltage range (V_{CC}):	
Device types 02, 05, 08, 11	-0.3 V dc to +7.0 V dc
Logic supply voltage range (V_{DD})	-0.3 V dc to +7.0 V dc
Input voltage range (V_{DR}):	
Device types 01, 03, 04, 06, 07, 09, 10	42 $V_{P,L-L}$
Device types 02, 05, 08, 11	10 $V_{P,L-L}$
Maximum power dissipation (P_D)	5 W
Logic voltage on any pin range (V_{IO})	-0.3 V dc to $V_{DD} + 0.3$ V dc
Logic latch-up immunity (I_{LU})	±150 mA
Logic input current (I_I)	±10 mA
Output current (I_O):	
Device types 01, 03, 04, 06, 07, 09, 10	190 mA
Device types 02, 05, 08, 11	1000 mA
Maximum junction temperature (T_J)	+150°C
Receiver common mode input voltage range (V_{IC}):	
Device types 01, 03, 04, 06, 07, 09, 10	-11 V dc to +11 V dc
Device types 02, 05, 08, 11	-5 V dc to +5 V dc
Lead temperature (soldering, 5 seconds)	+300°C
Thermal resistance junction-to-case (θ_{JC}): <u>3/</u>	
Cases X and Y	7°C/W

1/ This package contains 96 terminals on the bottom and 4 terminals on top of the package, see figure 1.

2/ Stresses above the listed absolute maximum rating may cause permanent damage to the device. This is a stress rating only, and functional operation of the device at these or any other conditions beyond limits indicated in the operational sections of this specification is not recommended. Extended operation at the maximum levels may degrade performance and affect reliability.

3/ Per MIL-STD-883, Method 1012.

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1.4 Recommended operating conditions.

Transceiver supply voltage range (V_{CC}):	
Device types 01, 03, 04, 06, 07, 09, 10	+4.75 V dc to +5.5 V dc
Device type 02	+4.75 V dc to +5.25 V dc
Device types 05, 08, 11	+4.5 V dc to +5.5 V dc
Logic supply voltage range (V_{DD})	+4.5 V dc to +5.5 V dc
Transceiver supply voltage range (V_{EE}):	
Device types 01, 04, 07, 10	-15 V dc
Device types 03, 06, 09	-12 V dc
Receiver differential voltage (V_{DR}):	
Device types 01, 03, 04, 06, 07, 09, 10	40 V_{P-P}
Device types 02, 05, 08, 11	8.0 V_{P-P}
Logic dc input voltage range (V_{IN})	0 V dc to V_{DD}
Receiver common mode input voltage (V_{IC}):	
Device types 01, 03, 04, 06, 07, 09, 10	± 10 V dc
Device types 02, 05, 08, 11	± 5.0 V dc
Driver peak output current (I_O):	
Device types 01, 03, 04, 06, 07, 09, 10	180 mA
Device types 02, 05, 08, 11	700 mA
Serial data rate range (S_D)	0 to 1 MHz
Clock duty cycle (D_C)	$50 \pm 5\%$
Case operating temperature range (T_C)	-55°C to $+125^\circ\text{C}$
Operating frequency (F_{IN})	24 MHz $\pm 0.01\%$

1.5 Radiation features.

Maximum total dose available dose rate = 50 – 300 rads (Si)/s:	
Device types 04, 10	100 Krad (Si)
Device type 05	1 Mrad (Si)
Device type 11	300 Krad (Si)
Single event phenomenon (SEP) :	
For device type 04:	
No SEL occurs at effective LET (see 4.4.4.2).....	$\leq 60 \text{ MeV-cm}^2/\text{mg}$ <u>1/</u>
No SEU occurs at effective LET	$\leq 36 \text{ MeV-cm}^2/\text{mg}$ <u>1/</u>
For device type 05:	
No SEL occurs at effective LET (see 4.4.4.2).....	$\leq 60 \text{ MeV-cm}^2/\text{mg}$ <u>1/</u>
No SEU occurs at effective LET	$\leq 36 \text{ MeV-cm}^2/\text{mg}$ <u>1/</u>
For device type 10:	
No SEL occurs at effective LET (see 4.4.4.2).....	$\leq 80 \text{ MeV-cm}^2/\text{mg}$ <u>1/</u>
No SEU occurs at effective LET	$\leq 16 \text{ MeV-cm}^2/\text{mg}$ <u>1/</u>
For device type 11:	
No SEL occurs at effective LET (see 4.4.4.2).....	$\leq 99 \text{ MeV-cm}^2/\text{mg}$ <u>1/</u>
No SEU occurs at effective LET	$\leq 16 \text{ MeV-cm}^2/\text{mg}$ <u>1/</u>

1.6 Digital logic testing for device classes Q and V.

Fault coverage measurement of manufacturing logic tests (MIL-STD-883, method 5012)	95.12 percent
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1/ Contact the manufacturer for SEP data. The SEP response is dependent upon the combination of protocol devices and transceiver devices.

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2. APPLICABLE DOCUMENTS

2.1 Government specification, standards, and handbooks. The following specification, standards, and handbooks form a part of this drawing to the extent specified herein. Unless otherwise specified, the issues of these documents are those cited in the solicitation or contract.

DEPARTMENT OF DEFENSE SPECIFICATION

MIL-PRF-38535 - Integrated Circuits, Manufacturing, General Specification for.

DEPARTMENT OF DEFENSE STANDARDS

MIL-STD-883 - Test Methods Standard Microcircuits.
MIL-STD-1835 - Interface Standard Electronic Component Case Outlines.

DEPARTMENT OF DEFENSE HANDBOOKS

MIL-HDBK-103 - List of Standard Microcircuit Drawings.
MIL-HDBK-780 - Standard Microcircuit Drawings.

(Copies of these documents are available online at <http://quicksearch.dla.mil/> or from the Standardization Document Order Desk, 700 Robbins Avenue, Building 4D, Philadelphia, PA 19111-5094.)

2.2 Non-Government publications. The following document(s) form a part of this document to the extent specified herein. Unless otherwise specified, the issues of the documents are the issues of the documents cited in the solicitation or contract.

THE INSTITUTE OF ELECTRICAL AND ELECTRONICS ENGINEERS (IEEE)

IEEE Standard 1149.1- IEEE Standard Test Access Port and Boundary Scan Architecture.

(Copies of these documents are available online at <http://www.ieee.org> or from the IEEE Service Center, 445 Hoes Lane, P.O. Box 1331, Piscataway, NJ 08855-1331.

ASTM INTERNATIONAL (ASTM)

ASTM F 1192 - Standard Guide for the Measurement of Single Event Phenomena (SEP) Induced by Heavy Ion Irradiation of Semiconductor Devices.

(Copies of this document is available online at <http://www.astm.org> or from ASTM International, P. O. Box C700, 100 Barr Harbor Drive, West Conshohocken, PA 19428-2959).

2.3 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing takes precedence. Nothing in this document, however, supersedes applicable laws and regulations unless a specific exemption has been obtained.

3. REQUIREMENTS

3.1 Item requirements. The individual item requirements for device classes Q and V shall be in accordance with MIL-PRF-38535 and as specified herein or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not affect the form, fit, or function as described herein.

3.2 Design, construction, and physical dimensions. The design, construction, and physical dimensions shall be as specified in MIL-PRF-38535 and herein for device classes Q and V.

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3.2.1 Case outlines. The case outlines shall be in accordance with 1.2.4 herein and figure 1.

3.2.2 Terminal connections. The terminal connections shall be as specified on figure 2.

3.2.3 Block diagram. The block diagram shall be as specified on figure 3.

3.2.4 Boundary scan instruction codes. The boundary scan instruction codes shall be as specified on figure 4.

3.2.5 Timing waveforms. The timing waveforms shall be as specified on figure 5.

3.2.6 Radiation exposure circuit. The radiation exposure circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing and acquiring activity upon request.

3.3 Electrical performance characteristics and postirradiation parameter limits. Unless otherwise specified herein, the electrical performance characteristics and postirradiation parameter limits are as specified in table IA and shall apply over the full case operating temperature range.

3.4 Electrical test requirements. The electrical test requirements shall be the subgroups specified in table IIA. The electrical tests for each subgroup are defined in table IA.

3.5 Marking. The part shall be marked with the PIN listed in 1.2 herein. In addition, the manufacturer's PIN may also be marked. For packages where marking of the entire SMD PIN number is not feasible due to space limitations, the manufacturer has the option of not marking the "5962-" on the device. For RHA product using this option, the RHA designator shall still be marked. Marking for device classes Q and V shall be in accordance with MIL-PRF-38535.

3.5.1 Certification/compliance mark. The certification mark for device classes Q and V shall be a "QML" or "Q" as required in MIL-PRF-38535.

3.6 Certificate of compliance. For device classes Q and V, a certificate of compliance shall be required from a QML-38535 listed manufacturer in order to supply to the requirements of this drawing (see 6.6.1 herein). The certificate of compliance submitted to DLA Land and Maritime -VA prior to listing as an approved source of supply for this drawing shall affirm that the manufacturer's product meets, for device classes Q and V, the requirements of MIL-PRF-38535 and herein.

3.7 Certificate of conformance. A certificate of conformance as required for device classes Q and V in MIL-PRF-38535 shall be provided with each lot of microcircuits delivered to this drawing.

3.8 IEEE 1149.1 compliance. These devices shall be compliant to IEEE 1149.1.

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TABLE IA. Electrical performance characteristics.

Test	Symbol	Test conditions <u>1/</u> -55°C ≤ T _C ≤ +125°C 4.5 V ≤ V _{DD} ≤ 5.5 V unless otherwise specified		Device type	Group A subgroups	Limits		Unit
						Min	Max	
Low level input voltage	V _{IL1}			All	1, 2, 3		0.8	V
Low level input voltage, TCK only	V _{IL2}			01, 02, 03, 04, 05, 06, 10, 11	1, 2, 3		0.8	
				07, 08, 09	1, 2, 3		0.7	
High level input voltage	V _{IH}			All	1, 2, 3	2.2		V
Low level input voltage <u>2/</u>	V _{ILC}			All	1, 2, 3		0.3V _{DD}	V
High level input voltage <u>2/</u>	V _{IHC}			All	1, 2, 3	0.7V _{DD}		V
Low level output voltage	V _{OL}	Output loads	I _{OL} = 4.0 mA	All	1, 2, 3		0.4	V
			I _{OL} = 1.0 μA <u>3/</u>				0.05	
High level output voltage	V _{OH}	Output loads	I _{OH} = 4.0 mA	All	1, 2, 3	2.4		V
			I _{OH} = 1.0 μA <u>3/</u>			V _{DD} -0.05		
Input leakage current	I _{IN}	TTL driven inputs	V _{IN} = V _{DD} or V _{SS}	All	1, 2, 3	-10	+10	μA
		Inputs with pull-up resistors	V _{IN} = V _{DD}				-10	
			V _{IN} = V _{SS}	01, 02, 03, 04, 05, 06, 10, 11	1, 2, 3	-900	-150	
				07, 08, 09		-167	-27	
Three-state output leakage current, TTL loaded outputs, single-drive buffer	I _{OZ}	V _O = V _{DD} or V _{SS}		All	1, 2, 3	-10	+10	μA
Short-circuit output current, output loads	I _{OS} <u>4/ 5/</u>	V _{DD} = 5.5 V, V _O = 0 V V _{DD} = 5.5 V, V _O = V _{DD}		All	1, 2, 3	-100	+100	mA
Input capacitance	C _{IN}	f = 1 MHz at 0 V See 4.4.1c		All	4		45	pF
Output capacitance	C _{OUT}			All	4		45	
Bi-directional capacitance <u>6/</u>	C _{IO}			All	4		45	
Standby operating current	I _{DDs}	f = 24 MHz		All	1, 2, 3		40	mA

See footnotes at end of table.

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TABLE IA. Electrical performance characteristics - Continued.

Test	Symbol	Test conditions $\frac{1}{-55^{\circ}\text{C} \leq T_{\text{C}} \leq +125^{\circ}\text{C}}$ $4.5\text{ V} \leq V_{\text{DD}} \leq 5.5\text{ V}$ unless otherwise specified		Device type	Group A subgroups	Limits		Unit			
						Min	Max				
Quiescent current <u>7/ 8/</u>	I _{DDQ}	f = 0 MHz		01 – 10	1, 3		35	μA			
					2		1	mA			
		Pre-irradiation level R		11	1, 3		35	μA			
					2		1	mA			
		Pre-irradiation level F		11	1, 3		35	μA			
					2		5	mA			
V _{CC} supply current	I _{CC}	V _{EE} = -12 V V _{CC} = 5 V	0% duty cycle (non-transmitting)	03, 06, 09	1, 2, 3		140	mA			
			50% duty cycle (f = 1 MHz) <u>9/</u>				140				
			100% duty cycle (f = 1 MHz) <u>9/</u>				140				
		V _{EE} = -15 V V _{CC} = 5 V	0% duty cycle (non-transmitting)	01, 04, 07, 10		140					
			50% duty cycle (f = 1 MHz) <u>10/</u>			140					
			100% duty cycle (f = 1 MHz) <u>10/</u>			140					
		V _{CC} = 5 V	0% duty cycle (non-transmitting)	02, 05, 08, 11	1, 2, 3		55				
			25% duty cycle <u>10/</u>				250				
			50% duty cycle (f = 1 MHz) <u>10/</u>				410				
			87.5% duty cycle (f = 1 MHz) <u>10/</u>				650				
			100% duty cycle (f = 500 kHz)			02			855		
			I _{EE} supply current	I _{EE}	V _{EE} = -12 V V _{CC} = 5 V	0% duty cycle (non-transmitting)	03, 06, 09		1, 2, 3		80
		50% duty cycle (f = 1 MHz) <u>9/</u>								180	
		100% duty cycle (f = 1 MHz) <u>9/</u>								270	
		V _{EE} = -15 V V _{CC} = 5 V			0% duty cycle (non-transmitting)	01, 04, 07, 10				80	
50% duty cycle (f = 1 MHz) <u>10/</u>					180						
100% duty cycle (f = 1 MHz) <u>10/</u>					270						

See footnotes at end of table.

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TABLE IA. Electrical performance characteristics - Continued.

Test	Symbol	Test conditions <u>1/</u> -55°C ≤ T _C ≤ +125°C 4.5 V ≤ V _{DD} ≤ 5.5 V unless otherwise specified	Device type	Group A subgroups	Limits		Unit
					Min	Max	
Functional tests		See 4.4.1b	All	7, 8			
Register write timing							
Address setup time <u>9/</u>	t _a	V _{CC} = minimum See figure 5.	All	9, 10, 11	0		ns
Data setup time <u>9/</u>	t _b		All	9, 10, 11	10		
Data hold time <u>9/</u>	t _c		All	9, 10, 11	8		
Address hold time <u>9/</u>	t _d		All	9, 10, 11	8		
$\overline{\text{CS}}\downarrow$ to $\overline{\text{CS}}\uparrow$ <u>9/</u>	t _e		All	9, 10, 11	105		
Access delay <u>9/ 11/ 12/</u>	t _f		All	9, 10, 11	85		
RD/ $\overline{\text{WR}}$ assertion to $\overline{\text{CS}}$ assertion <u>10/</u>	t _g		All	9, 10, 11	0		
$\overline{\text{CS}}$ negation to RD/ $\overline{\text{WR}}$ negation <u>10/</u>	t _h		All	9, 10, 11	0		
$\overline{\text{CS}}$ assertion to output enable <u>9/</u>	t _i		All	9, 10, 11	0	40	
$\overline{\text{CS}}$ negation to output three-state <u>10/</u>	t _j	All	9, 10, 11	5	35		
Register read timing							
Address setup time <u>9/</u>	t _a	V _{CC} = minimum See figure 5.	All	9, 10, 11	0		ns
$\overline{\text{CS}}$ assertion to output enable data valid <u>9/</u>	t _b		All	9, 10, 11		95	
$\overline{\text{CS}}$ negation to output disabled <u>10/</u>	t _c		All	9, 10, 11	5	35	
Address hold time <u>9/</u>	t _d		All	9, 10, 11	0		
$\overline{\text{CS}}$ assertion to output enable data invalid <u>9/</u>	t _e		All	9, 10, 11	0	40	
Access delay <u>9/ 11/ 12/</u>	t _f		All	9, 10, 11	45		
$\overline{\text{CS}}\downarrow$ to $\overline{\text{CS}}\uparrow$ <u>9/</u>	t _g		All	9, 10, 11	105		
Memory write timing							
Address propagation delay	t _a	V _{CC} = minimum See figure 5.	01–06, 10, 11	9, 10, 11	0	18	ns
			07, 08, 09	9, 10, 11	0	21	
Address valid to $\overline{\text{RCS}}$, RWR assertion <u>9/</u>	t _b		All	9, 10, 11	15	35	
See footnotes at end of table.							
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TABLE IA. Electrical performance characteristics - Continued.

Test	Symbol	Test conditions $\frac{1}{-55^{\circ}\text{C} \leq T_{\text{C}} \leq +125^{\circ}\text{C}}$ $4.5\text{ V} \leq V_{\text{DD}} \leq 5.5\text{ V}$ unless otherwise specified	Device type	Group A subgroups	Limits		Unit
					Min	Max	
Memory write timing – Continued							
$\overline{\text{DTACK}}$ setup time $\frac{9}{\text{ }}$	t_{c}	V_{CC} = minimum See figure 5.	All	9, 10, 11	10		ns
$\overline{\text{RCS}}$ and $\overline{\text{RWR}}$ hold time $\frac{9}{\text{ }}$ $\frac{13}{\text{ }}$	t_{d}		All	9, 10, 11	20	50	
Data propagation delay $\frac{9}{\text{ }}$	t_{e}		All	9, 10, 11	20	60	
Address hold time $\frac{9}{\text{ }}$	t_{g}		All	9, 10, 11	10	30	
$\overline{\text{DTACK}}$ hold time $\frac{9}{\text{ }}$	t_{h}		All	9, 10, 11	10		
$\overline{\text{RWR}}$ and $\overline{\text{RCS}}$ pulse width ($\overline{\text{DTACK}}$ tied to ground)	t_{i}		01–06, 10, 11	9, 10, 11	34		
			07, 08, 09	9, 10, 11	32		
$\overline{\text{RWR}}$ and $\overline{\text{RCS}} \uparrow$ to $\overline{\text{DMACK}} \uparrow$ $\frac{10}{\text{ }}$	t_{j}		All	9, 10, 11	15	125	
Data hold time $\frac{10}{\text{ }}$	t_{k}	All	9, 10, 11	10	40		
Memory read timing							
Address propagation delay	t_{a}	V_{CC} = minimum See figure 5.	01–06, 10, 11	9, 10, 11	0	18	ns
			07, 08, 09	9, 10, 11	0	21	
Address valid to $\overline{\text{RCS}}$, $\overline{\text{RRD}}$ assertion $\frac{9}{\text{ }}$	t_{b}		All	9, 10, 11	15	35	
$\overline{\text{DTACK}}$ setup time $\frac{9}{\text{ }}$	t_{c}		All	9, 10, 11	10		
$\overline{\text{RCS}}$ and $\overline{\text{RRD}}$ hold time $\frac{9}{\text{ }}$ $\frac{13}{\text{ }}$	t_{d}		All	9, 10, 11	20	50	
Data setup delay $\frac{9}{\text{ }}$	t_{e}		01-06	9, 10, 11	12		
			07, 08, 09	9, 10, 11	10		
			10, 11	9, 10, 11	14		
Data hold delay	t_{f}		01–06, 10, 11	9, 10, 11	0		
			07, 08, 09	9, 10, 11	2		
Address hold time $\frac{9}{\text{ }}$	t_{g}		All	9, 10, 11	10	30	

See footnotes at end of table.

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TABLE IA. Electrical performance characteristics - Continued.

Test	Symbol	Test conditions <u>1/</u> -55°C ≤ T _C ≤ +125°C 4.5 V ≤ V _{DD} ≤ 5.5 V unless otherwise specified	Device type	Group A subgroups	Limits		Unit	
					Min	Max		
Memory read timing - Continued								
$\overline{\text{DTACK}}$ hold time	t _h	V _{CC} = minimum See figure 5.	All	9, 10, 11	10		ns	
$\overline{\text{RRD}}$ and $\overline{\text{RCS}}$ pulse width ($\overline{\text{DTACK}}$ tied to ground)	t _i		01–06, 10, 11	9, 10, 11	34			
			07, 08, 09	9, 10, 11	32			
$\overline{\text{RRD}}$ and $\overline{\text{RCS}} \uparrow$ to $\overline{\text{DMACK}} \uparrow$ <u>10/</u>	t _j		All	9, 10, 11	15	45		
DMA timing								
$\overline{\text{TERACT}}$ assertion to $\overline{\text{DMAR}}$ assertion <u>10/</u>	t _a	V _{CC} = minimum See figure 5.	All	9, 10, 11	5		μs	
$\overline{\text{DMAR}}$ assertion to $\overline{\text{DMACK}}$ negation <u>10/</u>	t _b		Bus controller	01, 02, 03	9, 10, 11			7
				04-11	9, 10, 11			16
			Remote terminal	All	9, 10, 11			7
			Remote terminal with monitor	All	9, 10, 11			7
			Monitor	All	9, 10, 11			7
$\overline{\text{DMAG}}$ assertion to $\overline{\text{DMACK}}$ assertion <u>10/</u>	t _c		01–06, 10, 11	9, 10, 11	0	30	ns	
			07, 08, 09	9, 10, 11	5	30		
$\overline{\text{DMAG}}$ assertion to $\overline{\text{DMAR}}$ negation <u>10/</u>	t _d		All	9, 10, 11	0	35		
$\overline{\text{DMACK}}$ assertion to address bus active	t _e		01–06, 10, 11	9, 10, 11	0	5		
			07, 08, 09	9, 10, 11	-5	5		
$\overline{\text{DMACK}}$ assertion to $\overline{\text{DMAG}}$ negation <u>9/</u>	t _f		All	9, 10, 11	10			
$\overline{\text{DMACK}}$ negation to $\overline{\text{DMAR}}$ assertion <u>10/</u>	t _g		All	9, 10, 11	500			

See footnotes at end of table.

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TABLE IA. Electrical performance characteristics - Continued.

Test	Symbol	Test conditions <u>1/</u> -55°C ≤ T _C ≤ +125°C 4.5 V ≤ V _{DD} ≤ 5.5 V unless otherwise specified	Device type	Group A subgroups	Limits		Unit
					Min	Max	
DMA timing - Continued							
DMACK assertion to RAM control active (negated)	t _h	V _{CC} = minimum See figure 5.	01–06, 10, 11	9, 10, 11	0	5	ns
			07, 08, 09		-5	5	
DMACK negation to address three-state <u>10/</u>	t _i		All	9, 10, 11		5	
DMACK negation to RAM control disabled <u>10/</u>	t _j		All	9, 10, 11		5	
Power-up master reset timing							
MRST pulse width <u>10/</u>	t _a	V _{CC} = minimum See figure 5.	All	9, 10, 11	500		ns
MRST negation to ROMEN assertion <u>10/</u>	t _b		All	9, 10, 11		5	μs
MRST negation to READY assertion <u>10/</u>	t _c		All	9, 10, 11		10	μs
DMACK negation to ROMEN negation <u>10/</u>	t _d		All	9, 10, 11		500	ns
JTAG timing							
TCK frequency		See figure 5.	All	9, 10, 11		1	MHz
TCK period	t _a		All	9, 10, 11	1000		ns
TCK high time	t _b		All	9, 10, 11	1/2t _a		
TCK low time	t _c		All	9, 10, 11	1/2t _a		
TCK rise time	t _d		All	9, 10, 11		5	
TCK fall time	t _e		All	9, 10, 11		5	
TDI, TMS setup time	t _f		All	9, 10, 11	250		
TDI, TMS hold time	t _g		All	9, 10, 11	250		
TDO valid delay	t _h		All	9, 10, 11	250		
Receiver electrical characteristics							
Differential (receiver) input impedance <u>10/</u>	R _{IZ}	V _{CC} = minimum, see figure 5 Input f = 1 MHz (no transformer in circuit)	01, 03, 04, 06, 07, 09, 10	1, 2, 3	15		kΩ
Common mode input voltage <u>10/</u>	V _{IC}	V _{CC} = minimum, see figure 5 Direct-coupled stub, input 1.2 V _{PP} , 200 ns rise/fall time ±25 ns, f = 1 MHz	01, 03, 04, 06, 07, 09, 10	1, 2, 3	-10	+10	V
			02, 05, 08, 11	1, 2, 3	-5	+5	

See footnotes at end of table.

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TABLE IA. Electrical performance characteristics - Continued.

Test	Symbol	Test conditions <u>1/</u> -55°C ≤ T _C ≤ +125°C 4.5 V ≤ V _{DD} ≤ 5.5 V unless otherwise specified	Device type	Group A subgroups	Limits		Unit
					Min	Max	
Receiver electrical characteristics - Continued							
Common mode rejection ratio <u>10/</u>	CMRR	V _{CC} = minimum, see figure 5.	All	1, 2, 3	Pass/Fail <u>14/</u>		N/A
Input threshold voltage (no response)	V _{TH1}	V _{CC} = minimum, see figure 5. Transformer-coupled stub, input at f = 1 MHz, rise/fall time 200 ns (receiver output 0 → 1 transition) <u>10/</u>	All	1, 2, 3		0.20	V _{PP,L-L}
		V _{CC} = minimum, see figure 5. Direct-coupled stub, input at f = 1 MHz, rise/fall time 200 ns (receiver output 0 → 1 transition)	All	1, 2, 3		0.28	
Input threshold voltage (response)	V _{TH2}	V _{CC} = minimum, see figure 5. Transformer-coupled stub, input at f = 1 MHz, rise/fall time 200 ns (receiver output 0 → 1 transition) <u>10/</u>	All	1, 2, 3	0.86	14.0	V _{PP,L-L}
		V _{CC} = minimum, see figure 5. Direct-coupled stub, input at f = 1 MHz, rise/fall time 200 ns (receiver output 0 → 1 transition)	All	1, 2, 3	1.20	20.0 <u>10/</u>	
Differential input voltage level	V _{IDR}	V _{CC} = minimum, see figure 5.	02	1, 2, 3		8.0	V _{P-P}
Transmitter electrical characteristics							
Output voltage swing	V _O	V _{CC} = minimum, see figure 5. Transformer-coupled stub, point A, input f = 1 MHz, R _L = 70Ω <u>10/</u>	All	1, 2, 3	18	27	V _{PP,L-L}
		V _{CC} = minimum, see figure 5. Direct-coupled stub, point A, input f = 1 MHz, R _L = 35Ω	All	1, 2, 3	6.0	9	
		V _{CC} = minimum, see figure 5. Point A, input f = 1 MHz, R _L = 35Ω <u>10/</u>	All	1, 2, 3	6.0	20	
Output noise voltage differential <u>10/</u>	V _{NS}	V _{CC} = minimum, see figure 5. Transformer-coupled stub, point A, input f = DC to 10 MHz, R _L = 70Ω	All	1, 2, 3		14	mV-RMS _{L-L}
		V _{CC} = minimum, see figure 5. Direct-coupled stub, point A, input f = DC to 10 MHz, R _L = 35Ω	All	1, 2, 3		5	

See footnotes at end of table.

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TABLE IA. Electrical performance characteristics - Continued.

Test	Symbol	Test conditions <u>1/</u> -55°C ≤ T _C ≤ +125°C 4.5 V ≤ V _{DD} ≤ 5.5 V unless otherwise specified	Device type	Group A subgroups	Limits		Unit
					Min	Max	
Transmitter electrical characteristics - Continued							
Output symmetry <u>15/</u>	V _{OS}	V _{CC} = minimum Transformer-coupled stub, point A, R _L = 70Ω, measurement taken 2.5 μs after end of transmission <u>10/</u>	All	1, 2, 3	-250	+250	mV _{PP,L-L}
		V _{CC} = minimum Direct-coupled stub, point A, R _L = 35Ω, measurement taken 2.5 μs after end of transmission <u>16/</u>	All	1, 2, 3	-90	+90	
Output voltage distortion (overshoot or ring)	V _{DIS}	V _{CC} = minimum, see figure 5. Transformer-coupled stub, point A, R _L = 70Ω <u>10/</u>	01, 03– 1	1, 2, 3	-900	+900	mV _{peak,L-L}
			02	1, 2, 3	-2.0	+2.0	V _{peak,L-L}
		V _{CC} = minimum, see figure 5. Direct-coupled stub, point A, R _L = 35Ω <u>16/</u>	01, 03–11	1, 2, 3	-300	+300	mV _{peak,L-L}
			02	1, 2, 3	-1.0	+1.0	V _{peak,L-L}
Terminal input impedance <u>10/</u>	T _{IZ}	V _{CC} = minimum, see figure 5. Transformer-coupled stub, point A, input f = 75 kHz to 1 MHz, (power on or power off, non- transmitting, R _L removed from circuit)	All	1, 2, 3	1		kΩ
		V _{CC} = minimum, see figure 5. Direct-coupled stub, point A, input f = 75 kHz to 1 MHz, (power on or power off, non- transmitting, R _L removed from circuit)	All	1, 2, 3	2		

AC electrical characteristics

Transmitter output rise/fall time	t _R , t _F	V _{CC} = minimum, see figure 5. Input f = 1 MHz 50% duty cycle: direct-coupled, R _L = 35Ω, output at 10% through 90% points TXOUT, $\overline{\text{TXOUT}}$	All	9, 10, 11	100	300	ns
Zero crossing distortion	t _{RZCD}	V _{CC} = minimum, see figure 5. Direct-coupled stuff, Input f = 1 MHz, 3 V _{PP} (skew input ±150 ns), rise/fall time 200 ns	All	9, 10, 11	-150	+150	

See footnotes at end of table.

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TABLE IA. Electrical performance characteristics - Continued.

Test	Symbol	Test conditions 1/ -55°C ≤ T _C ≤ +125°C 4.5 V ≤ V _{DD} ≤ 5.5 V unless otherwise specified	Device type	Group A subgroups	Limits		Unit
					Min	Max	
AC electrical characteristics - Continued							
Zero crossing stability	t _{TZCS}	V _{CC} = minimum, see figure 5. Input TXIN and TXIN should create transmitter output zero crossings at 500 ns, 1000 ns, 1500 ns, and 2000 ns. These zero crossings should not deviate more than ±25 ns	All	9, 10, 11	-25	+25	ns

^{1/} Device type 04 RHA devices supplied to this drawing have been characterized through all levels M, D, P, L, and R of irradiation. Device type 05 RHA devices supplied to this drawing have been characterized through all levels M, D, P, L, R, F, G, and H of irradiation. However, the 04 and 05 devices are only tested at the 'R' and 'H' level, respectively. Device type 10 RHA devices supplied to this drawing have been characterized through all levels M, D, P, L, and R of irradiation. However, this device is only be tested at the R level. Device type 11 RHA devices supplied to this drawing have been characterized through all levels M, D, P, L, R, and F of irradiation. However, this device is only tested at the R or F level supplied. Pre and post irradiation values are identical unless otherwise specified in table IA. When performing post irradiation electrical measurements for any RHA level, T_A = +25°C. All testing to be performed using worst case test conditions unless otherwise specified. GND may not vary from 0 V by more than ±50 mV. Unless otherwise specified, V_{CC} = 5.0 V ±5% for device type 02; V_{CC} = 5.0 V ±10% for device types 05, 08, and 11; V_{CC} = 5.0 V +10%, -5% and V_{EE} = -12.0 V or -15.0 V ±5% for device types 01, 03, 04, 06, 07, 09, and 10.

^{2/} 24 MHz input only.

^{3/} The worst case test condition is when I_{OL} and I_{OH} = 4.0 mA.

^{4/} Supplied as a design limit but not guaranteed or tested.

^{5/} Not more than one output may be shorted at a time for maximum duration of one second.

^{6/} For all pins except CHA, CHA, CHB, CHB.

^{7/} All inputs tied to V_{DD}.

^{8/} Post irradiation limit is 1.0 mA. Device type 11 post irradiation limit is 1.0 mA level R of irradiation and 5.0 mA level F of irradiation.

^{9/} For device types 07, 08, and 09, this parameter is guaranteed, but not tested.

^{10/} Guaranteed by characterization but not tested.

^{11/} Read cycle followed by a read cycle - minimum 45 ns.

Read cycle followed by a write cycle - minimum 45 ns.

Write cycle followed by a read cycle - minimum 85 ns.

Write cycle followed by a write cycle - minimum 85 ns.

^{12/} Minimum pulse width from latter rising edge of RD/ $\overline{\text{WR}}$ or $\overline{\text{CS}}$ to first falling edge.

^{13/} Pulse width duration is measured with respect to the device recognizing DTACK assertion.

^{14/} Pass/fail criteria per the test method described in MIL-STD-1553, appendix A. RT validation test plan, section 5.1.2.2, common mode rejection.

^{15/} Test in accordance with the method described in MIL-STD-1553B output symmetry, section 4.5.2.1.1.4.

^{16/} Tested on device types 07, 08, and 09 only.

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TABLE IB. SEP test limits. 1/ 2/ 3/

Device type	Bias $V_{DD} = 4.5 \text{ V}$		Bias $V_{DD} = 5.5 \text{ V}$ For latch-up test no SEL effective LET = 4/
	Effective LET no upsets (SEU) [MeV/(mg/cm ²)]	Maximum device cross section	
04	≤ 36	$1.6 \times 10^{-6} \text{ cm}^2/\text{bit}$	≤ 60
05	≤ 36	$1.6 \times 10^{-6} \text{ cm}^2/\text{bit}$	≤ 60
10	≤ 16	$1.5 \times 10^{-4} \text{ cm}^2/\text{device}$	≤ 80
11	≤ 16	$1.5 \times 10^{-4} \text{ cm}^2/\text{device}$	≤ 99

1// For SEP test conditions, see 4.4.4.2 herein.

2/ Technology characterization and model verification supplemented by in-line data may be used in lieu of end-of-line testing. Test plan must be approved by TRB and qualifying activity.

3/ Used worst case assumption for Adam's 90% Geosynchronous Orbit and device error rate can be calculated as follows:

- a) For device types 04 and 05: Device error rate = 7.2×10^{-5} errors/device-day
- b) For device types 10 and 11: Device error rate = 7.0×10^{-6} errors/device-day

4/ Worst case temperature for latchup test, $T_A = +125^\circ\text{C} \pm 10^\circ\text{C}$

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Figure 1: Mechanical drawing of the package showing top, side, and detail views. The top view shows dimensions A, B, C, D, E, and F. The side view shows dimensions A1, L, and C. The detail view shows dimensions D1, D2, D3, D4, D5, D6, D7, D8, D9, D10, D11, D12, D13, D14, D15, D16, D17, D18, D19, D20, D21, D22, D23, D24, D25, D26, D27, D28, D29, D30, D31, D32, D33, D34, D35, D36, D37, D38, D39, D40, D41, D42, D43, D44, D45, D46, D47, D48, D49, D50, D51, D52, D53, D54, D55, D56, D57, D58, D59, D60, D61, D62, D63, D64, D65, D66, D67, D68, D69, D70, D71, D72, D73, D74, D75, D76, D77, D78, D79, D80, D81, D82, D83, D84, D85, D86, D87, D88, D89, D90, D91, D92, D93, D94, D95, D96, D97, D98, D99, D100. The drawing includes a table of dimensions and a note: "DIE OUTLINES SHOWN FOR REFERENCE ONLY 3 PLS".

⊕	∅.030	M	C	A	M	B	M
⊕	∅.010	M	C				

Case X				
Symbol	Millimeters		Inches	
	Min	Max	Min	Max
A	6.85	8.00	.270	.315
A1	2.54	3.17	.100	.125
b	0.40	0.50	.016	.020
D	32.89	33.66	1.295	1.325
D1	29.21 BSC		1.150 BSC	
E	26.54	27.30	1.045	1.075
e	1.27 BSC		.050 BSC	
L	4.37	4.77	.172	.188

FIGURE 1. Case outlines

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Technical drawing of a ceramic package showing top, bottom, and detail views with dimensions and callouts.

Top View: Shows the package layout with dimensions $E1$, $D1$, and L . The central area is labeled "TOP VIEW". Dimensions 100 , 76 , 75 , 51 , 26 , and 50 are indicated. A "MARK" is shown on the left side.

Bottom View: Shows the package layout with dimensions 2.300 REF TYP and $D2/E2$. The central area is labeled "BOTTOM VIEW". Dimensions 25 , 1 , 100 , 76 , 75 , 51 , and 50 are indicated.

Detail B: Shows a cross-section of the package with dimensions $.035$ MAX, $.075$ MAX, $.035$ REF, and $.050$ REF. The text "SEE NOTE 2" is present.

Other Callouts:

- $.060$ DIA TYP ALL CORNER HOLES IN METAL TIEBAR
- $.020 \times 45^\circ$ 3 PLACES
- $.008 \pm .006$ (CERAMIC EDGE)
- $.035 \pm .005$
- LEAD WIDTH 100 PLACES
- LEAD THICKNESS
- SEE DETAIL B

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Case Y				
Symbol	Millimeters		Inches	
	Min	Max	Min	Max
A		2.66		.105
A1	2.28	3.30	.090	.130
b	0.152	0.254	.006	.010
c	0.1270	0.1905	.0050	.0075
D/E		65.532		2.580
D1	33.91	34.67	1.335	1.365
D2/E2	15.24 BSC		.600 BSC	
E1	24.64	25.40	.970	1.000
e	0.635 BSC		.025 BSC	
L	8.89		.350	

NOTE:

1. The US Government preferred system of measurement is the metric SI system. However, this item was originally designed using inch-pound units of measurements. In the event of conflict between the metric and inch-pound units, the inch-pound units shall take precedence.
2. Lead repair is optional. This view shows the drawn portion of the lead that must be reside within these dimensions. The shape of the repaired lead (as shown) is for reference only.

FIGURE 1. Case outlines - Continued.

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Device type	All						
Case outline	X						
Terminal number	Terminal symbol	Terminal number	Terminal symbol	Terminal number	Terminal symbol	Terminal number	Terminal symbol
A2	A15	C2	A12	T1	A3	V1	V _{SS}
A4	A14	C4	V _{DD}	T3	A4	V3	$\overline{\text{RRD}}$
A6	A13	C6	A8	T5	V _{DD}	V5	D14
A8	$\overline{\text{ROMEN}}$	C8	V _{SS}	T7	A6	V7	$\overline{\text{DTACK}}$
A10	$\overline{\text{CS}}$	C10	$\overline{\text{DMAG}}$	T9	24 MHz	V9	D13
A12	MSEL0	C12	$\overline{\text{YF_INT}}$	T11	V _{SS}	V11	D15
A14	TCK	C14	TMS	T13	$\overline{\text{LOCK}}$	V13	D9
A16	TDI	C16	A/B STD	T15	$\overline{\text{READY}}$	V15	D10
A18	TDO	C18	$\overline{\text{CHB}}$	T17	GND	V17	D8
A20	RTA2	C20	GND	T19	V _{CC}	V19	D1
A22	RTA0	C22	CHB	T21	V _{EE} $\frac{1}{2}$	V21	D2
A24	GND	C24	V _{CC}	T23	V _{EE} $\frac{1}{2}$	V23	D0
B1	V _{DD}	D1	A9	U2	A1	W2	A5
B3	A11	D3	A7	U4	V _{DD}	W4	$\overline{\text{RWR}}$
B5	A10	D5	V _{SS}	U6	A2	W6	A0
B7	$\overline{\text{DMACK}}$	D7	V _{DD}	U8	V _{SS}	W8	TCLK
B9	$\overline{\text{AUTOEN}}$	D9	$\overline{\text{MSG_INT}}$	U10	D12	W10	V _{DD}
B11	RD/ $\overline{\text{WR}}$	D11	V _{SS}	U12	D11	W12	$\overline{\text{RCS}}$
B13	MSEL1	D13	$\overline{\text{DMAR}}$	U14	$\overline{\text{SSYSF}}$	W14	D5
B15	$\overline{\text{TRST}}$	D15	$\overline{\text{MRST}}$	U16	$\overline{\text{TERACT}}$	W16	D6
B17	RTA4	D17	GND	U18	$\overline{\text{CHA}}$	W18	D7
B19	RTA3	D19	V _{CC}	U20	GND	W20	D4
B21	RTA1	D21	V _{EE} $\frac{1}{2}$	U22	CHA	W22	D3
B23	RTPTY	D23	V _{EE} $\frac{1}{2}$	U24	V _{CC}	W24	GND
Terminal located on top of package							
CP1	V _{DDQ}	CP2	V _{SSQ}	CP3	V _{DD}	CP4	V _{SS}

$\frac{1}{2}$ Device types 01, 03, 04, 06, 07, 09, and 10 only. For device types 02, 05, 08, and 11, this is a N/C (no connection).

FIGURE 2. Terminal connections.

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Device type	All						
Case outline	Y						
Terminal number	Terminal symbol	Terminal number	Terminal symbol	Terminal number	Terminal symbol	Terminal number	Terminal symbol
1	$\overline{\text{DMACK}}$	26	A15	51	TDI	76	V _{DD}
2	$\overline{\text{DMAG}}$	27	V _{EE} 1/	52	TDO	77	V _{SS}
3	$\overline{\text{DMAR}}$	28	V _{EE} 1/	53	$\overline{\text{TRST}}$	78	$\overline{\text{ROMEN}}$
4	$\overline{\text{DTACK}}$	29	GND	54	RTPTY	79	$\overline{\text{AUTOEN}}$
5	V _{SS}	30	V _{CC}	55	RTA0	80	$\overline{\text{CS}}$
6	$\overline{\text{RRD}}$	31	GND	56	RTA1	81	RD/ $\overline{\text{WR}}$
7	$\overline{\text{RWR}}$	32	CHA	57	RTA2	82	D0
8	$\overline{\text{RCS}}$	33	$\overline{\text{CHA}}$	58	RTA3	83	D1
9	V _{DD}	34	GND	59	RTA4	84	D2
10	V _{SS}	35	V _{CC}	60	V _{DD}	85	D3
11	A0	36	V _{CC}	61	V _{SS}	86	D4
12	A1	37	GND	62	V _{DD}	87	D5
13	A2	38	GND	63	$\overline{\text{TERACT}}$	88	D6
14	A3	39	V _{CC}	64	$\overline{\text{READY}}$	89	D7
15	A4	40	V _{CC}	65	$\overline{\text{MSG_INT}}$	90	D8
16	A5	41	GND	66	$\overline{\text{YF_INT}}$	91	D9
17	A6	42	CHB	67	V _{SS}	92	D10
18	A7	43	$\overline{\text{CHB}}$	68	TCLK	93	D11
19	A8	44	GND	69	$\overline{\text{LOCK}}$	94	D12
20	A9	45	V _{CC}	70	A/ $\overline{\text{B}}$ STD	95	D13
21	A10	46	GND	71	MSEL0	96	D14
22	A11	47	V _{EE} 1/	72	MSEL1	97	D15
23	A12	48	V _{EE} 1/	73	$\overline{\text{MRST}}$	98	V _{SS}
24	A13	49	TCK	74	24 MHz	99	V _{DD}
25	A14	50	TMS	75	$\overline{\text{SSYSF}}$	100	V _{DD}

1/ Device types 01, 03, 04, 06, 07, 09, and 10 only. For device types 02, 05, 08, and 11, this is a N/C (no connection).

FIGURE 2. Terminal connections - Continued.

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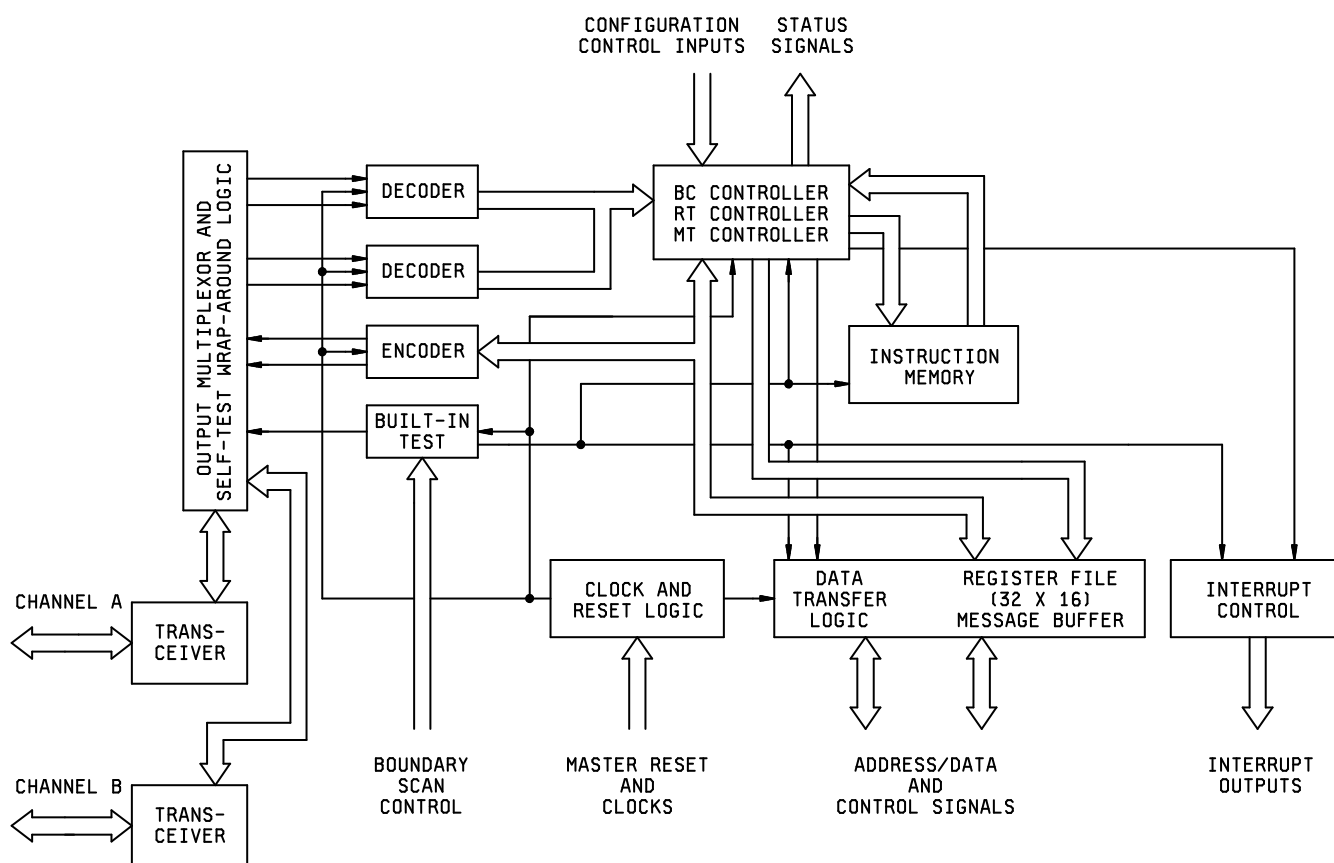


FIGURE 3. Block diagram.

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Device types 01, 02, 03, 04, 05, 06, 10, 11	
Instruction name	Instruction code
BYPASS	1111
SAMPLE/PRELOAD	0010
EXTEST	0000
INTEST	0001
RUNBIST	0111
IDCODE	0100
GL-TRISTATE	0011
INTERNAL-SCAN	0101
PRIVATE	0110
USER-SELECTABLE	1000 → 1110

Device types 07, 08, 09	
Instruction name	Instruction code
BYPASS	1111
SAMPLE/PRELOAD	0010
EXTEST	0000

FIGURE 4. Boundary scan instruction codes.

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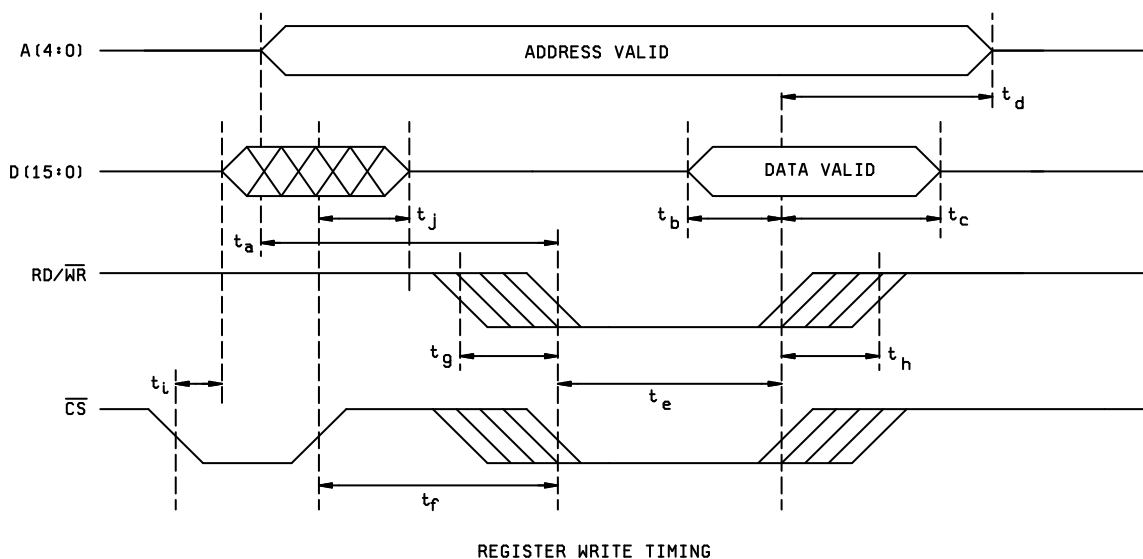
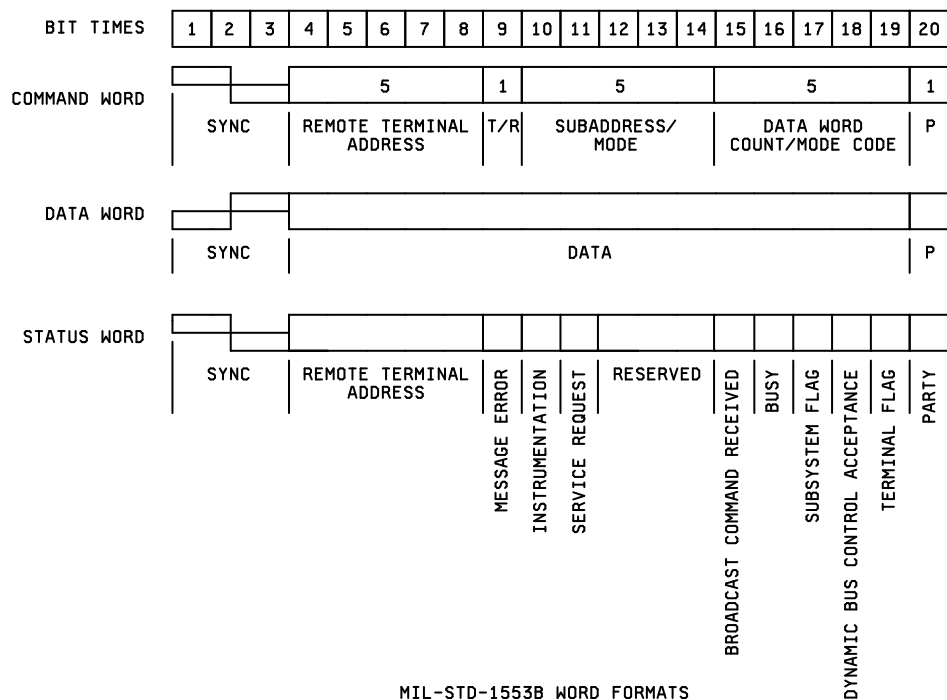


FIGURE 5. Timing waveforms.

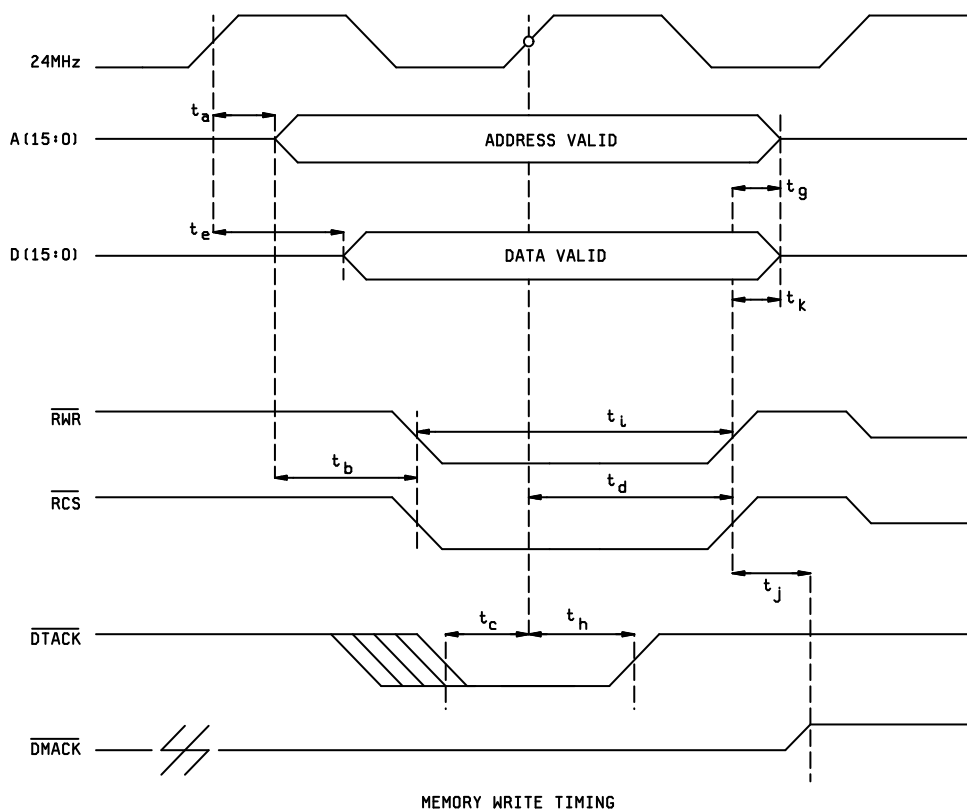
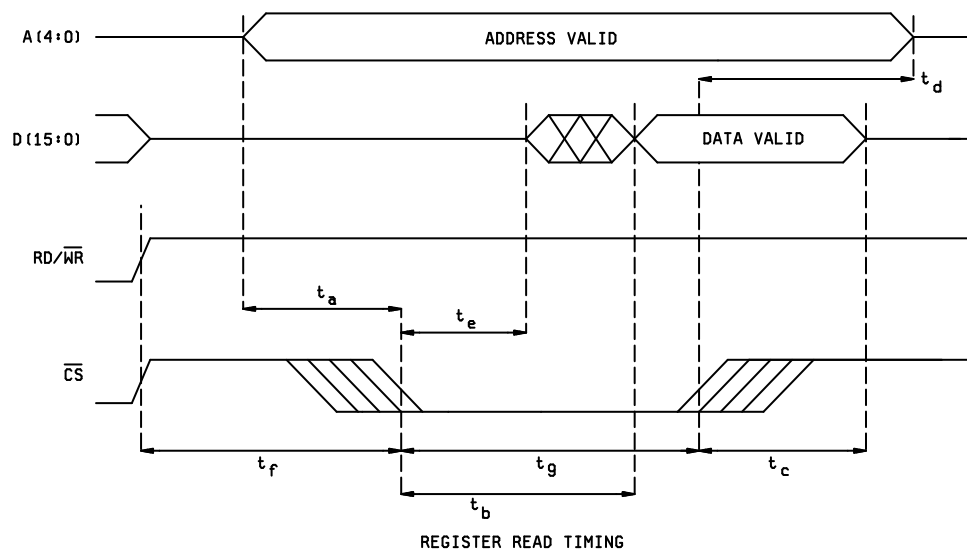
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NOTE: The memory read and write timing diagrams are applicable for reads and writes resulting from the auto-initialization sequence.

FIGURE 5. Timing waveforms - Continued.

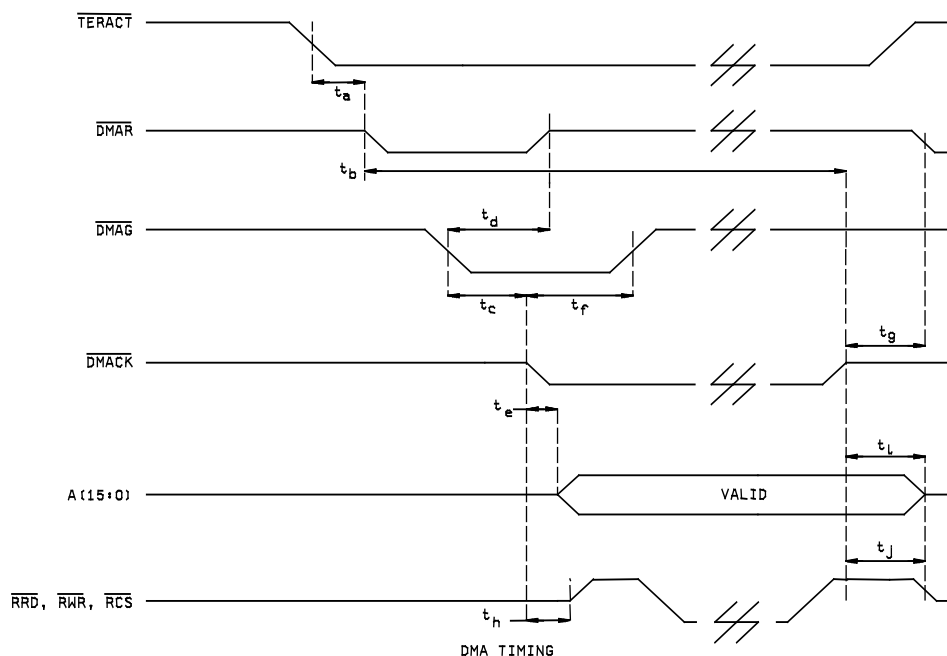
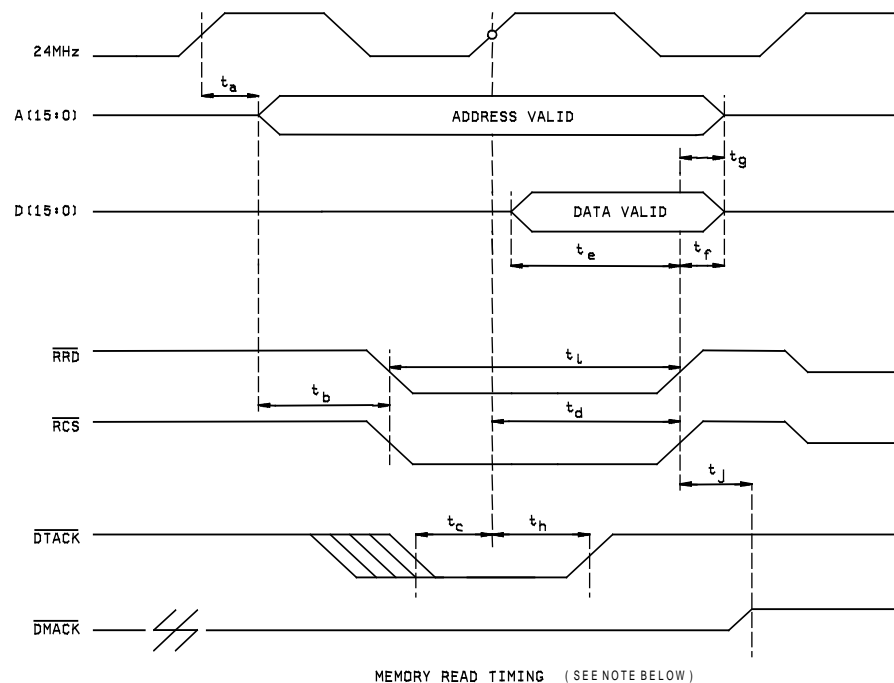
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NOTE: The memory read and write timing diagrams are applicable for reads and writes resulting from the auto-initialization sequence.

FIGURE 5. Timing waveforms - Continued.

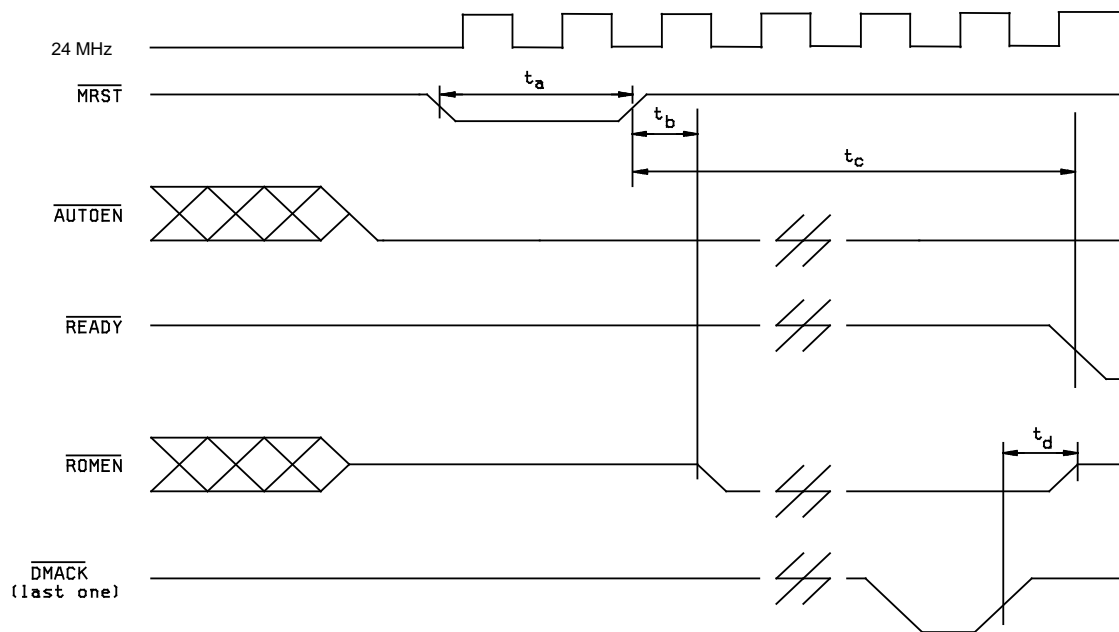
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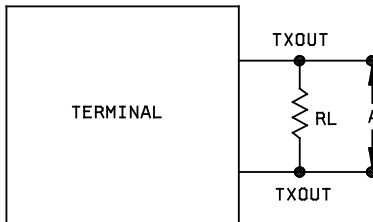
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POWER-UP MASTER RESET TIMING



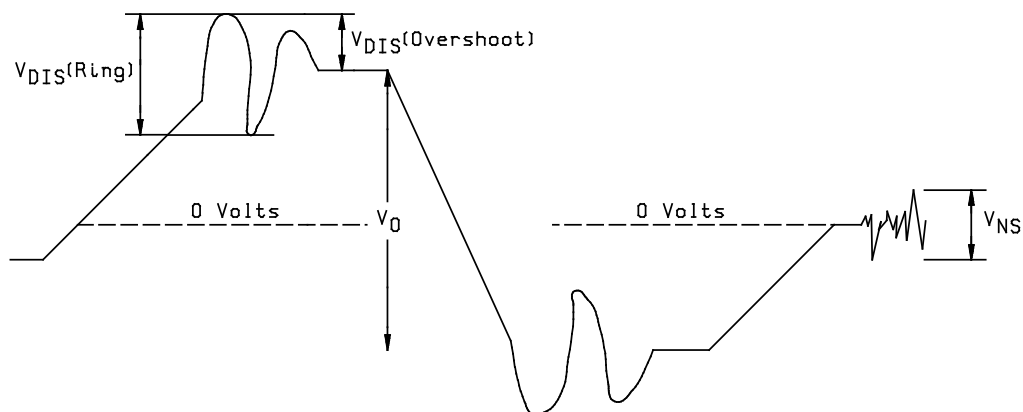
TRANSCEIVER TEST CIRCUIT MIL-STD-1553B

NOTES:

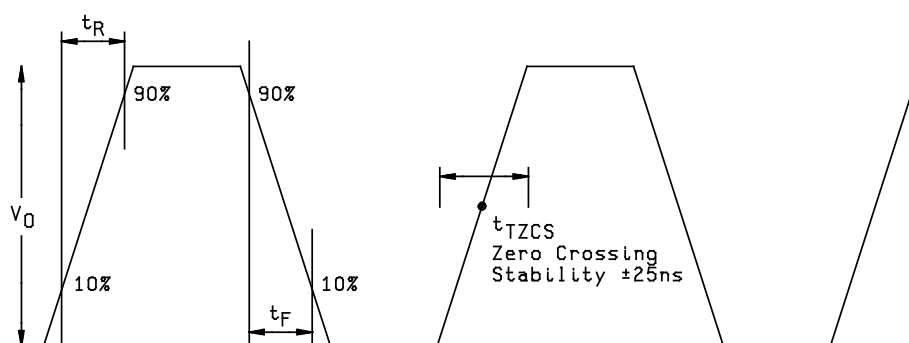
1. Transformer coupled stub:
Terminal is defined as transceiver plus isolation transformer.
2. Direct coupled stub:
Terminal is defined as transceiver plus isolation transformer and fault resistors.

FIGURE 5. Timing waveforms - Continued.

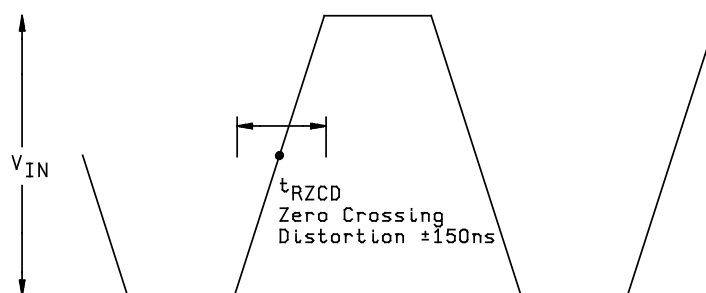
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TRANSMITTER OUTPUT CHARACTERISTICS (V_{DIS} , V_{NS} , V_O)



TRANSMITTER OUTPUT ZERO CROSSING STABILITY (t_{TZCS} , t_R , t_F)



RECEIVER INPUT ZERO CROSSING DISTORTION (t_{RZCD})

FIGURE 5. Timing waveforms - Continued.

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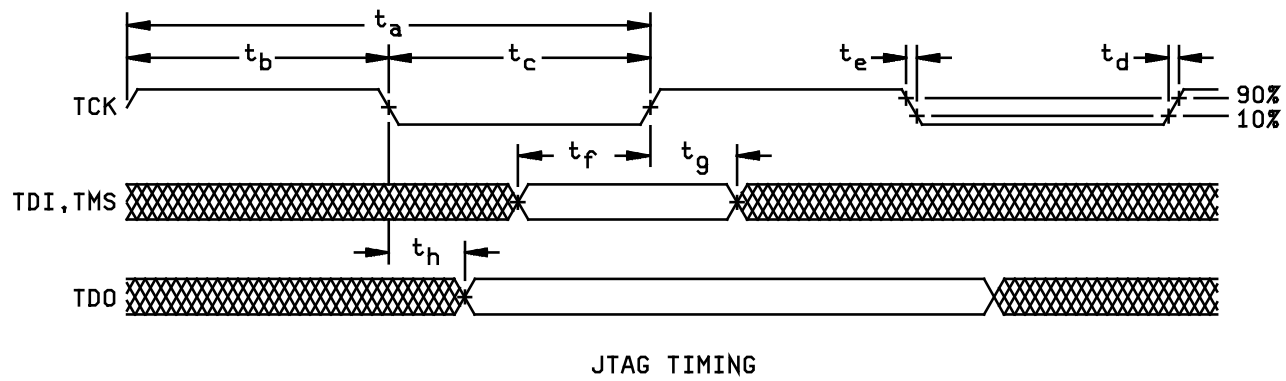


FIGURE 5. Timing waveforms - Continued.

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4. VERIFICATION

4.1 Sampling and inspection. For device classes Q and V, sampling and inspection procedures shall be in accordance with MIL-PRF-38535 or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not affect the form, fit, or function as described herein.

4.2 Screening. For device classes Q and V, screening shall be in accordance with MIL-PRF-38535, and shall be conducted on all devices prior to qualification and technology conformance inspection.

4.2.1 Additional criteria for device classes Q and V.

- a. The burn-in test duration, test condition and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-PRF-38535. The burn-in test circuit shall be maintained under document revision level control of the device manufacturer's Technology Review Board (TRB) in accordance with MIL-PRF-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1015 of MIL-STD-883.
- b. Interim and final electrical test parameters shall be as specified in table IIA herein.
- c. Additional screening for device class V beyond the requirements of device class Q shall be as specified in MIL-PRF-38535, appendix B.

4.3 Qualification inspection for device classes Q and V. Qualification inspection for device classes Q and V shall be in accordance with MIL-PRF-38535. Inspections to be performed shall be those specified in MIL-PRF-38535 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.4).

4.4 Conformance inspection. Technology conformance inspection for classes Q and V shall be in accordance with MIL-PRF-38535 including groups A, B, C, D, and E inspections and as specified (see 4.4.1 through 4.4.4).

4.4.1 Group A inspection.

- a. Tests shall be as specified in table IIA herein.
- b. For device classes Q and V, subgroups 7 and 8 shall include verifying the functionality of the device; these tests shall have been fault graded in accordance with MIL-STD-883, method 5012 (see 1.6 herein).
- c. Subgroup 4 (C_{IN} , C_{OUT} , and C_{IO}) shall be measured only for the initial test and after process or design changes which may affect capacitance. A minimum sample of 5 devices with zero failures shall be required.

4.4.2 Group C inspection. The group C inspection end-point electrical parameters shall be as specified in table IIA herein.

4.4.2.1 Additional criteria for device classes Q and V. The steady-state life test duration, test condition and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-PRF-38535. The test circuit shall be maintained under document revision level control by the device manufacturer's TRB in accordance with MIL-PRF-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1005 of MIL-STD-883.

4.4.3 Group D inspection. The group D inspection end-point electrical parameters shall be as specified in table IIA herein.

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TABLE IIA. Electrical test requirements.

Test requirements	Subgroups (in accordance with MIL-STD-883, method 5005, table I)	Subgroups (in accordance with MIL-PRF-38535, table III)	
	Device class M	Device class Q	Device class V
Interim electrical parameters (see 4.2)	---	---	---
Final electrical parameters (see 4.2)	1, 2, 3, 7, 8, 9, 10, 11 <u>1/</u>	1, 2, 3, 7, 8, 9, 10, 11 <u>1/</u>	1, 2, 3, 7, 8, 9, 10, 11 <u>2/ 3/</u>
Group A test requirements (see 4.4)	1, 2, 3, 4, 7, 8, 9, 10, 11	1, 2, 3, 4, 7, 8, 9, 10, 11	1, 2, 3, 4, 7, 8, 9, 10, 11
Group C end-point electrical parameters (see 4.4)	1, 7, 9	1, 7, 9	1, 7, 9
Group D end-point electrical parameters (see 4.4)	1, 7, 9	1, 7, 9	1, 7, 9
Group E end-point electrical parameters (see 4.4)	1, 7, 9	1, 7, 9	1, 7, 9

1/ PDA of 10% applies to subgroup 1.

2/ PDA of 10% applies to subgroups 1 and 7.

3/ Delta limits, as specified in table IIB herein, shall be required when specified and the delta values shall be completed with reference to the zero hour electrical parameters.

TABLE IIB. Burn-in and operating life test, delta parameters (+25°C).

Parameter	Symbol	Delta limits
Quiescent current	I _{DDQ}	±10% of measured values or 35 µA whichever is greater

NOTE: If the device is tested at or below 35 µA, no deltas are required.

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4.4.4 Group E inspection. Group E inspection is required only for parts intended to be marked as radiation hardness assured (see 3.5 herein).

- a. End-point electrical parameters shall be as specified in table IIA herein.
- b. For device classes Q and V, the devices or test vehicle shall be subjected to radiation hardness assured tests as specified in MIL-PRF-38535 for the RHA level being tested. For device class M, the devices shall be subjected to radiation hardness assured tests as specified in MIL-PRF-38535, appendix A for the RHA level being tested. All device classes must meet the post irradiation end-point electrical parameter limits as defined in table IA at $T_A = +25^{\circ}\text{C} \pm 5^{\circ}\text{C}$, after exposure, to the subgroups specified in table IIA herein.

4.4.4.1 Total dose irradiation testing. Total dose irradiation testing shall be performed in accordance with MIL-STD-883 method 1019, condition A, and as specified herein.

4.4.4.1.1 Accelerated annealing test. Accelerated annealing tests shall be performed on all devices requiring a RHA level greater than 5k rads(Si). The post-anneal end-point electrical parameter limits shall be as specified in table IA herein and shall be the pre-irradiation end-point electrical parameter limit at $25^{\circ}\text{C} \pm 5^{\circ}\text{C}$. Testing shall be performed at initial qualification and after any design or process changes which may affect the RHA response of the device.

4.4.4.2 Single event phenomena (SEP). When specified in the purchase order or contract, SEP testing shall be performed on class V devices. SEP testing shall be performed on the Standard Evaluation Circuit (SEC) or alternate SEP test vehicle as approved by the qualifying activity at initial qualification and after any design or process changes which may affect the upset or latchup characteristics. Test four devices with zero failures. ASTM F1192 may be used as a guideline when performing SEP testing. The test conditions for SEP are as follows:

- a. The ion beam angle of incidence shall be between normal to the die surface and 60° to the normal, inclusive (i.e. $0^{\circ} \leq \text{angle} \leq 60^{\circ}$). No shadowing of the ion beam due to fixturing or package related effects is allowed.
- b. The fluence shall be ≥ 100 errors or $\geq 10^7$ ions/cm².
- c. The flux shall be between 10^2 and 10^5 ions/cm²/s. The cross-section shall be verified to be flux independent by measuring the cross-section at two flux rates which differ by at least an order of magnitude.
- d. The particle range shall be ≥ 20 microns in silicon.
- e. The test upset temperature shall be $+25^{\circ}\text{C}$ and the latchup test temperature shall be the maximum rated operating temperature $\pm 10^{\circ}\text{C}$.
- f. Bias conditions shall be $V_{DD} = 4.5$ V dc for the upset measurements and $V_{DD} = 5.5$ V dc for the latchup measurements.
- g. For SEP test limits, see table IB herein.

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5. PACKAGING

5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-PRF-38535 for device classes Q and V.

6. NOTES

6.1 Intended use. Microcircuits conforming to this drawing are intended for use for Government microcircuit applications (original equipment), design applications, and logistics purposes.

6.1.1 Replaceability. Microcircuits covered by this drawing will replace the same generic device covered by a contractor prepared specification or drawing.

6.1.2 Substitutability. Device class Q devices will replace device class M devices.

6.2 Configuration control of SMD's. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished using DD Form 1692, Engineering Change Proposal.

6.3 Record of users. Military and industrial users should inform DLA Land and Maritime when a system application requires configuration control and which SMD's are applicable to that system. DLA Land and Maritime will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronic devices (FSC 5962) should contact DLA Land and Maritime -VA, telephone (614) 692-8108.

6.4 Comments. Comments on this drawing should be directed to DLA Land and Maritime -VA, Columbus, Ohio 43218-3990, or telephone (614) 692-0540.

6.5 Abbreviations, symbols, and definitions. The abbreviations, symbols, and definitions used herein are defined in MIL-PRF-38535 and MIL-HDBK-1331.

6.6 Sources of supply.

6.6.1 Sources of supply for device classes Q and V. Sources of supply for device classes Q and V are listed in QML-38535. The vendors listed in QML-38535 have submitted a certificate of compliance (see 3.6 herein) to DLA Land and Maritime -VA and have agreed to this drawing.

6.7 Additional information. When specified in the purchase order or contract, a copy of the following additional data shall be supplied:

- a. RHA test conditions (SEP).
- b. Number of upsets (SEU).
- c. Number of transients (SET).
- d. Occurrence of latchup (SEL).

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TABLE III. Pin descriptions.

Name	Type <u>1</u> /	Active <u>2</u> /	Description
Data bus			
D0	TTB	--	Bit 0 (LSB) of the bi-directional Data bus.
D1	TTB	--	Bit 1 of the bi-directional Data bus.
D2	TTB	--	Bit 2 of the bi-directional Data bus.
D3	TTB	--	Bit 3 of the bi-directional Data bus.
D4	TTB	--	Bit 4 of the bi-directional Data bus.
D5	TTB	--	Bit 5 of the bi-directional Data bus.
D6	TTB	--	Bit 6 of the bi-directional Data bus.
D7	TTB	--	Bit 7 of the bi-directional Data bus.
D8	TTB	--	Bit 8 of the bi-directional Data bus.
D9	TTB	--	Bit 9 of the bi-directional Data bus.
D10	TTB	--	Bit 10 of the bi-directional Data bus.
D11	TTB	--	Bit 11 of the bi-directional Data bus.
D12	TTB	--	Bit 12 of the bi-directional Data bus.
D13	TTB	--	Bit 13 of the bi-directional Data bus.
D14	TTB	--	Bit 14 of the bi-directional Data bus.
D15	TTB	--	Bit 15 (MSB) of the bi-directional Data bus.
Address bus			
A0	TTB	--	Bit 0 (LSB) of the bi-directional Address bus.
A1	TTB	--	Bit 1 of the bi-directional Address bus.
A2	TTB	--	Bit 2 of the bi-directional Address bus.
A3	TTB	--	Bit 3 of the bi-directional Address bus.
A4	TTB	--	Bit 4 of the bi-directional Address bus.
A5	TTO	--	Bit 5 of the Address bus.
A6	TTO	--	Bit 6 of the Address bus.
A7	TTO	--	Bit 7 of the Address bus.
A8	TTO	--	Bit 8 of the Address bus.
A9	TTO	--	Bit 9 of the Address bus.
A10	TTO	--	Bit 10 of the Address bus.
A11	TTO	--	Bit 11 of the Address bus.
A12	TTO	--	Bit 12 of the Address bus.
A13	TTO	--	Bit 13 of the Address bus.
A14	TTO	--	Bit 14 of the Address bus.
A15	TTO	--	Bit 15 (MSB) of the Address bus.

See footnotes at end of table.

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TABLE III. Pin descriptions - Continued.

Name	Type <u>1/</u>	Active <u>2/</u>	Description
Remote terminal address inputs			
RTA0	TUI	--	Remote Terminal Address bit 0. This is bit 0 of the RT address. This is the least significant bit for the RT address.
RTA1	TUI	--	Remote Terminal Address bit 1. This is bit 1 of the RT address.
RTA2	TUI	--	Remote Terminal Address bit 2. This is bit 2 of the RT address.
RTA3	TUI	--	Remote Terminal Address bit 3. This is bit 3 of the RT address.
RTA4	TUI	--	Remote Terminal Address bit 4. This is the most significant bit of the RT address.
RTPTY	TUI	--	Remote Terminal Parity. This is an odd parity input for the RT address.
JTAG testability pins			
TDO	TTO	--	TDO. This output performs the operation of Test Data Output as defined in the IEEE Standard 1149.1. This cell provides the output signal for the Test Access Port (TAP). This non-inverting output buffer is optimized for driving TTL loads.
TCK	TI	--	TCK. This input performs the operation of Test Clock input as defined in the IEEE Standard 1149.1. This cell provides the input clock for non-inverting input buffer that is optimized for driving TTL input levels.
TMS	TUI	--	TMS. This input performs the operation of Test Mode Select as defined in the IEEE Standard 1149.1. This cell provides the input signal for the Test Access Port (TAP). This non-inverting input buffer is optimized for driving TTL input levels.
TDI	TUI	--	TDI. This input performs the operation of Test Data In as defined in the IEEE Standard 1149.1. This cell provides the input signal for the Test Access Port (TAP). This non-inverting input buffer is optimized for driving TTL input levels.
$\overline{\text{TRST}}$	TUI	AL	$\overline{\text{TRST}}$. This input provides the RESET to the TAP controller as defined in the IEEE Standard 1149.1. This non-inverting input buffer is optimized for driving TTL input levels. When not exercising JTAG, tie $\overline{\text{TRST}}$ to a logical 0.
Biphase inputs/outputs			
CHA	DIO	--	Channel A (true). This is the Manchester-encoded true signal for channel A.
$\overline{\text{CHA}}$	DIO	--	Channel A (complement). This is the Manchester-encoded complement signal for channel A.
CHB	DIO	--	Channel B (true). This is the Manchester-encoded true signal for channel B.
$\overline{\text{CHB}}$	DIO	--	Channel B (complement). This is the Manchester-encoded complement signal for channel B.
DMA signals			
$\overline{\text{DMAR}}$	TTO <u>3/</u>	AL	DMA Request. This signal is asserted when access to RAM is required. It goes inactive upon request of the $\overline{\text{DMAG}}$ signal.
$\overline{\text{DMAG}}$	TI	AL	DMA Grant. Once this input is received, the device is allowed to access RAM.
$\overline{\text{DMACK}}$	TTO <u>3/</u>	AL	DMA Acknowledge. This signal is asserted by the device to indicate the receipt of $\overline{\text{DMAG}}$. The signal remains active until all RAM bus activity is completed.
$\overline{\text{DTACK}}$	TI	AL	Data Transfer Acknowledge. This pin indicates that a data transfer is to occur and that the device may complete the memory cycle.

See footnotes at end of table.

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TABLE III. Pin descriptions - Continued.

Name	Type <u>1/</u>	Active <u>2/</u>	Description															
Control signals																		
RD/ \overline{WR}	TI	--	Read/Write. This indicates the direction of data flow with respect to the host. A logic high signal means the host is trying to read data from the device, and a logic low signal means the host is trying to write data to the device.															
\overline{CS}	TI	AL	Chip Select. This pin selects the device when accessing the internal registers.															
\overline{RRD}	TTO	AL	RAM Read. This signal is generated by the device to read data from RAM.															
\overline{RWR}	TTO	AL	RAM Write. This signal is generated by the device to write data to RAM.															
\overline{RCS}	TTO	AL	RAM Chip Select. This signal is used in conjunction with the $\overline{RRD}/\overline{RWR}$ signal to access RAM.															
\overline{AUTOEN}	TI	AL	Auto Enable. This pin, when active, enables automatic initialization.															
\overline{ROMEN}	TTO <u>3/</u>	AL	ROM Enable. This pin, when active enables the ROM for automatic initialization applications.															
\overline{SSYSF}	TI	AL	Subsystem Fail. Upon receipt, this signal propagates directly to the RT 1553 status word.															
24 MHz	CI	--	24 MHz Clock. This 24 MHz input clock requires a 50% \pm 10% duty cycle with an accuracy of \pm 0.01%.															
\overline{MRST}	TUI	AL	Master Reset. This input pin resets the internal encoders, decoders, all register, and associated logic.															
MSEL1	TI	--	Mode Select 1. This pin is the most significant bit for the mode select. For proper mode selection, see below: <table><tr><td><u>MSEL1</u></td><td><u>MSEL0</u></td><td><u>Mode of Operation</u></td></tr><tr><td>0</td><td>0</td><td>Bus Controller = SBC</td></tr><tr><td>0</td><td>1</td><td>Remote Terminal = SRT</td></tr><tr><td>1</td><td>0</td><td>Monitor Terminal = SMT</td></tr><tr><td>1</td><td>1</td><td>SMT/SRT</td></tr></table>	<u>MSEL1</u>	<u>MSEL0</u>	<u>Mode of Operation</u>	0	0	Bus Controller = SBC	0	1	Remote Terminal = SRT	1	0	Monitor Terminal = SMT	1	1	SMT/SRT
<u>MSEL1</u>	<u>MSEL0</u>	<u>Mode of Operation</u>																
0	0	Bus Controller = SBC																
0	1	Remote Terminal = SRT																
1	0	Monitor Terminal = SMT																
1	1	SMT/SRT																
MSEL0	TI	--	Mode Select 0. This pin is the least significant bit for the mode select. (See MSEL1 for proper logic states.)															
TCLK	TI	--	Timer Clock. This internal timer is a 16-bit counter with a 64 μ s resolution when using the 24 MHz input clock. For different applications, the user may input a clock (0-60 MHz) to establish the timer resolution. (Duty Cycle = 50% \pm 10%).															
A/ \overline{B} STD	TI	--	Military Standard A or B. This pin defines whether the device will be used a MIL-STD-1553A or 1553B mode of operation.															
\overline{LOCK}	TI	AL	Lock. This pin, when set active, prevents software changes to both the RT address, A/ \overline{B} STD, and mode select.															

See footnotes at end of table.

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TABLE III. Pin descriptions - Continued.

Name	Type <u>1/</u>	Active <u>2/</u>	Description
Status signals			
$\overline{\text{TERACT}}$	TO	AL	Terminal Active. This output pin indicates that the terminal is actively processing a 1553 command.
$\overline{\text{MSG_INT}}$	TTO <u>3/</u>	AL	Message Interrupt. This pin is active for three clock cycles (i. e., 125 ns pulse) upon the occurrence of interrupt events which are enabled.
$\overline{\text{YF_INT}}$	TTO <u>3/</u>	AL	You Failed Interrupt. This pin is active for three clock cycles (i. e., 125 ns pulse) upon the occurrence of interrupt events which are enabled.
$\overline{\text{READY}}$	TO	AL	Ready. This signal indicates the device has completed initialization or BIT, and regular execution may begin.
Power/Ground			
V_{DD}	--	--	+5 volt logic power ($\pm 10\%$)
V_{CC}	--	--	Device types 01, 03, 04, 06, 07, 09, and 10: +5 volt transceiver power (+10%, -5%). Recommended de-coupling capacitors: 4.7 μF and 0.1 μF . Device type 02: +5 volt transceiver power ($\pm 5\%$). Device types 05, 08, and 11: +5 volt transceiver power ($\pm 10\%$). Recommended de-coupling capacitors: 4.7 μF and 0.1 μF .
V_{EE}	--	--	Device types 01, 03, 04, 06, 07, 09, and 10 only: -12 or -15 volt transceiver power ($\pm 5\%$). Recommended de-coupling capacitors: 4.7 μF and 0.1 μF .
V_{SS}	--	--	Digital ground.
GND	--	--	Transceiver ground.

1/ TO = TTL output

TTB = Three-state TTL bi-directional

CI = CMOS input

TUI = TTL input (internally pulled high)

TI = TTL input

TTO = Three-state TTL output

DIO = Differential input/output

All pins specified as TTL are actually CMOS transistor pairs designed for TTL compatibility.

2/ AH = Active high

AL = Active low

3/ High impedance and active low.

**STANDARD
MICROCIRCUIT DRAWING**
DLA LAND AND MARITIME
COLUMBUS, OHIO 43218-3990

SIZE
A

5962-94663

REVISION LEVEL
K

SHEET
37

STANDARD MICROCIRCUIT DRAWING BULLETIN

DATE: 13-05-20

Approved sources of supply for SMD 5962-94663 are listed below for immediate acquisition information only and shall be added to MIL-HDBK-103 and QML-38535 during the next revision. MIL-HDBK-103 and QML-38535 will be revised to include the addition or deletion of sources. The vendors listed below have agreed to this drawing and a certificate of compliance has been submitted to and accepted by DLA Land and Maritime -VA. This information bulletin is superseded by the next dated revision of MIL-HDBK-103 and QML-38535. DLA Land and Maritime maintains an online database of all current sources of supply at <http://www.landandmaritime.dla.mil/Programs/Smcr/>.

Standard microcircuit drawing PIN <u>1</u> /	Vendor CAGE number	Vendor similar PIN <u>2</u> /
5962-9466301QXA	<u>3</u> /	UT69151LX15/GA
5962-9466301QYA	<u>3</u> /	UT69151LX15/WA
5962-9466301QXC	<u>3</u> /	UT69151LX15/GC
5962-9466301QYC	<u>3</u> /	UT69151LX15/WC
5962-9466302QXA	<u>3</u> /	UT69151DX/GA
5962-9466302QYA	<u>3</u> /	UT69151DX/WA
5962-9466302QXC	<u>3</u> /	UT69151DX/GC
5962-9466302QYC	<u>3</u> /	UT69151DX/WC
5962-9466303QXA	<u>3</u> /	UT69151LX12/GA
5962-9466303QYA	<u>3</u> /	UT69151LX12/WA
5962-9466303QXC	<u>3</u> /	UT69151LX12/GC
5962-9466303QYC	<u>3</u> /	UT69151LX12/WC
5962-9466304QXA	<u>3</u> /	UT69151LXE15/GQA
5962-9466304QYA	<u>3</u> /	UT69151LXE15/WQA
5962-9466304QXC	<u>3</u> /	UT69151LXE15/GQC
5962-9466304QYC	<u>3</u> /	UT69151LXE15/WQC
5962R9466304QXA	<u>3</u> /	UT69151LXE15/GQAR
5962R9466304QYA	<u>3</u> /	UT69151LXE15/WQAR
5962R9466304QXC	<u>3</u> /	UT69151LXE15/GQCR
5962R9466304QYC	<u>3</u> /	UT69151LXE15/WQCR
5962R9466304VXA	<u>3</u> /	UT69151LXE15/GVAR
5962R9466304VYA	<u>3</u> /	UT69151LXE15/WVAR
5962R9466304VXC	<u>3</u> /	UT69151LXE15/GVCR
5962R9466304VYC	<u>3</u> /	UT69151LXE15/WVCR
5962-9466305QXA	<u>3</u> /	UT69151DXE/GQA
5962-9466305QYA	<u>3</u> /	UT69151DXE/WQA
5962-9466305QXC	<u>3</u> /	UT69151DXE/GQC
5962-9466305QYC	<u>3</u> /	UT69151DXE/WQC

See footnotes at end of table.

STANDARD MICROCIRCUIT DRAWING BULLETIN - Continued.

DATE: 13-05-20

Standard microcircuit drawing PIN <u>1</u> /	Vendor CAGE number	Vendor similar PIN <u>2</u> /
5962H9466305QXA	<u>3</u> /	UT69151DXE/GQAH
5962H9466305QYA	<u>3</u> /	UT69151DXE/WQAH
5962H9466305QXC	<u>3</u> /	UT69151DXE/GQCH
5962H9466305QYC	<u>3</u> /	UT69151DXE/WQCH
5962H9466305VXA	<u>3</u> /	UT69151DXE/GVAH
5962H9466305VYA	<u>3</u> /	UT69151DXE/WVAH
5962H9466305VXC	<u>3</u> /	UT69151DXE/GVCH
5962H9466305VYC	<u>3</u> /	UT69151DXE/WVCH
5962-9466306QXA	<u>3</u> /	UT69151LXE12/GQA
5962-9466306QYA	<u>3</u> /	UT69151LXE12/WQA
5962-9466306QXC	<u>3</u> /	UT69151LXE12/GQC
5962-9466306QYC	<u>3</u> /	UT69151LXE12/WQC
5962-9466307QXA	<u>3</u> /	UT69151LXE15/GQA
5962-9466307QYA	<u>3</u> /	UT69151LXE15/WQA
5962-9466307QXC	<u>3</u> /	UT69151LXE15/GQC
5962-9466307QYC	<u>3</u> /	UT69151LXE15/WQC
5962-9466308QXA	65342	UT69151DXE/GQA
5962-9466308QYA	65342	UT69151DXE/WQA
5962-9466308QXC	65342	UT69151DXE/GQC
5962-9466308QYC	65342	UT69151DXE/WQC
5962-9466309QXA	<u>3</u> /	UT69151LXE12/GQA
5962-9466309QYA	<u>3</u> /	UT69151LXE12/WQA
5962-9466309QXC	<u>3</u> /	UT69151LXE12/GQC
5962-9466309QYC	<u>3</u> /	UT69151LXE12/WQC
5962R9466310QYA	<u>3</u> /	UT69151LXE15/WQAR
5962R9466310QYC	<u>3</u> /	UT69151LXE15/WQCR
5962R9466310VYA	<u>3</u> /	UT69151LXE15/WVAR
5962R9466310VYC	<u>3</u> /	UT69151LXE15/WVCR
5962R9466311QYA	65342	UT69151DXE/WQAR
5962R9466311QYC	65342	UT69151DXE/WQCR
5962R9466311VYA	65342	UT69151DXE/WVAR
5962R9466311VYC	65342	UT69151DXE/WVCR

See footnotes at end of table.

STANDARD MICROCIRCUIT DRAWING BULLETIN - Continued.

DATE: 13-05-20

Standard microcircuit drawing PIN <u>1/</u>	Vendor CAGE number	Vendor similar PIN <u>2/</u>
5962F9466311QYA	65342	UT69151DXE/WQAF
5962F9466311QYC	65342	UT69151DXE/WQCF
5962F9466311VYA	65342	UT69151DXE/WVAF
5962F9466311VYC	65342	UT69151DXE/WVCF

1/ The lead finish shown for each PIN representing a hermetic package is the most readily available from the manufacturer listed for that part. If the desired lead finish is not listed, contact the vendor to determine its availability.

2/ Caution. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.

3/ Not available from an approved source of supply.

Vendor CAGE
number

65342

Vendor name
and address

Aeroflex Colorado Springs, Inc.
4350 Centennial Boulevard
Colorado Springs, CO 80907-3486

The information contained herein is disseminated for convenience only and the Government assumes no liability whatsoever for any inaccuracies in the information bulletin.